

Serial No. 09/116,138

TI-24953

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE****VIA FACSIMILE: (703) 305-3431****(703) 305-3432**

Applicants: Anthony et al.

Serial No.: 09/116,138

Art Unit: 2814

Filed: 15 July 1998

Examiner: Bernard Su

For: High Permittivity Silicate Gate Dielectric

**AMENDMENT PURSUANT TO 37 C.F.R. § 1.111**

Assistant Commissioner for Patents

Washington, DC 20231

Dear Sir:

As a result of a telephone conversation between the undersigned and Examiner Su on this date, Applicants request that the subject application be amended as follows:

**IN THE CLAIMS**

Please cancel Claims 31-35 without prejudice.

**REMARKS**

Claims 31-35 of this application are being canceled by this paper as being drawn to a device, while Claims 1-30, drawn to a method, and Claims 36-40, drawn to a product by process, remain in the application.

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Prompt examination of this application in view of the election of Claims 1-30 and 36-40 is respectfully requested.

Respectfully submitted,



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6 August 1999